

1N4942G THRU 1N4948G

GLASS PASSIVATED JUNCTION FAST SWITCHING RECTIFIER
Reverse Voltage - 200 to 1000 Volts
Forward Current - 1.0 Ampere

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- For use in high frequency rectifier circuits
- Fast switching for high efficiency
- Glass passivated cavity-free junction
- Capable of meeting environmental standards of MIL-S-19500
- 1.0 ampere operation at T_A=55 [™]C with no thermal runaway
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3Kg) tension

Mechanical Data

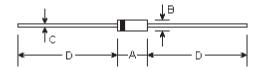
 Case: DO-41 molded plastic over glass body
 Terminals: Plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.012 ounce, 0.335 gram

DO-41



DIMENSIONS									
DIM	inches		m	Note					
	Min.	Max.	Min.	Max.	Note				
Α	0.165	0.205	4.2	5.2					
В	0.079	0.106	2.0	2.7	ф				
С	0.028	0.034	0.71	0.86	ф				
D	1.000	-	25.40	-					

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

	Symbols	1N 4942G	1N 4944G	1N 4946G	1N 4947G	1N 4948G	Units
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	140	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	200	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at $\rm T_A$ =55 $^{\circ}\rm C$	I _(AV)	1.0					Amp
Peak forward surge current 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method)	I _{FSM}	25.0					Amps
Maximum instantaneous forward voltage at 1.0A	V _F	1.30					Volts
Maximum DC reverse current at rated DC blocking voltage T _A =150°C	I _R	1.0 200.0					μА
Maximum reverse recovery time (Note 1)	T _{rr}	150 250 500		500	nS		
Typical junction capacitance (Note 2)	C _J	15.0					ρF
Typical thermal resistance (Note 3)	R _{⊕JA}		°C/W				
Operating junction and storage temperature range	T _J , T _{STG}		°C				

Notes:

- (1) Reverse recovery test conditions: I_c=0.5A, I_g=1.0A, I_g=0.25A
- (2) Measured at 1.0MHz and applied reverse voltage of 4.0 volts
- (3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

RATINGS AND CHARACTERISTIC CURVES

